



Article New Scaling Laws for Pinning Force Density in Superconductors

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Abstract: Since the report by Fietz and Webb (Phys. Rev. 1968, 178, 657–667), who considered the pinning force density, $\vec{F_p} = \vec{J_c} \times \vec{B}$ (where J_c is the critical current density and B is applied magnetic flux density), in isotropic superconductors as a unique function of reduced magnetic field, $\frac{B}{B_{\sigma}}$ (where B_{c2} is the upper critical field), $\left| \overrightarrow{F_p} \right|$ has been scaled based on the $\frac{B}{B_{c2}}$ ratio, for which there is a widely used Kramer–Dew–Hughes scaling law of $\left|\vec{F_p}(B)\right| = F_{p,max} \left(\frac{B}{B_{c2}}\right)^p \left(1 - \frac{B}{B_{c2}}\right)^q$, where $F_{p,max}$, B_{c2} , *p*, and *q* are free-fitting parameters. To describe $|\vec{F_p}(B)|$ in high-temperature superconductors, the Kramer–Dew–Hughes scaling law has been modified by (a) an assumption of the angular dependence of all parameters and (b) by the replacement of the upper critical field, B_{c2} , by the irreversibility field, B_{irr} . Here, we note that $\vec{F_p}$ is also a function of critical current density, and thus, the $\left|\vec{F_p}(J_c)\right|$ scaling law should exist. In an attempt to reveal this law, we considered the full $\left| \vec{F_p}(B, J_c) \right|$ function and reported that there are three distinctive characteristic ranges of $\left(\frac{B}{B_{c2}}, \frac{J_c}{I_c(sf)}\right)$ (where $J_c(sf)$ is the self-field critical current density) on which $\left|\vec{F_p}(B, J_c)\right|$ can be splatted. Several new scaling laws for $\left|\vec{F_p}(J_c)\right|$ were proposed and applied to MgB₂, NdFeAs(O,F), REBCO, (La,Y)H₁₀, and YH₆. The proposed scaling laws describe the in-field performance of superconductors at low and moderate magnetic fields, and thus, the primary niche for these laws is superconducting wires and tapes for cables, fault current limiters, and transformers.

Keywords: pinning force density in superconductors; superconducting critical current; scaling laws in superconductivity

1. Introduction

In 1962, Philip W. Anderson wrote [1], "A major difficulty in understanding hard superconductors has been the appreciable temperature dependence of critical currents and fields at temperatures as low as $0.1 \cdot T_c$. None of the properties of the bulk superconducting state vary noticeably at this temperature . . .

... We shall show that this ... can be explained by assuming that the mechanism of flux creep is thermally activated motion of bundles of flux lines, aided by the Lorentz $\vec{x} = \vec{x}$

force $J \otimes B$, over free energy barriers coming from the pinning effect of inhomogeneities, strains, dislocations, or other physical defects".

Since then, the primary idea that the origin of the electric power dissipation in type-II superconductors is Abrikosov's vortices dissipative movement under the Lorentz force [2]

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Copyright: © 2022 by the author. Licensee MDPI, Basel, Switzerland. This article is an open access article distributed under the terms and conditions of the Creative Commons Attribution (CC BY) license (https:// creativecommons.org/licenses/by/ 4.0/). has been unconditionally accepted. Based on this concept, superconducting materials can be characterized by principal quantity, the pinning force density, $\vec{F_p}$, defined as:

$$F_{p}(B, J_{c}, T) = J_{c}(B, T) \otimes B$$
(1)

where $J_c(B,T)$ is the experimentally measured critical current density and *B* is the applied magnetic flux density.

There is a need to clarify that because F_p is a mechanical force density (which is directly related to the Lorenz force density) applied to the superconducting sample, it is not impossible to build a machine, which will directly measure this mechanical force density with simultaneous measurements of:

- 1. The electric field, *E*, along the sample;
- 2. The applied magnetic field, B_{appl} ;
- 3. The sample temperature, *T*;
- 4. The transport current density, J.

Direct $\vec{F_p}$ measurements in this machine will utilize (*E*, *B*_{appl}, *T*, *J*) as independent experimental parameters. Despite the fact that the utilizing now methods of $\vec{F_p}$ determination are based on the multiplication of the critical current density, $J_c(B_{appl})$, and the applied magnetic field, B_{appl} , it does not alter the fundamental nature of $\vec{F_p}$ (see, for instance, [1]) and a principal possibility to measure $\vec{F_p}$ directly. Thus, a conventional way of thinking that $\vec{F_p}$ is another representation of the measured in the experiment $J_c(B_{appl})$ and B_{appl} can be reconsidered to be more broad.

Fietz and Webb [3] were the first to propose a scaling law for pinning force density:

$$\left|\vec{F_p}\right| = \left|\vec{F_p}(B)\right| = K \times k(\kappa) \times B_{c2}^{5/2} \times g\left(\frac{B}{B_{c2}}\right)$$
(2)

where *K* is a numerical multiplicative prefactor, k(x) is a function where the independent variable is the Ginzburg–Landau parameter κ , B_{c2} is the upper critical field, and g(x) is a function of a reduced applied magnetic field. Several years later, Kramer [4] and

Dew-Hughes [5] developed the most widely used expression for $|\vec{F_p}|$:

$$\left|\vec{F_p}(B)\right| = F_{p,max} \times \left(\frac{B}{B_{c2}}\right)^p \times \left(1 - \frac{B}{B_{c2}}\right)^q \tag{3}$$

where $F_{p,max}$, B_{c2} , p, and q are free-fitting parameters. It should mention that Equation (3) is in use in its normalized form of [6]:

$$\left|\vec{f_{p,n}}(B)\right| = \frac{(p+q)^{p+q}}{p^p \cdot q^q} \times \left(\frac{B}{B_{c2}}\right)^p \times \left(1 - \frac{B}{B_{c2}}\right)^q \tag{4}$$

For Nb₃Sn-based alloys, Equation (3) was upgraded [7–11] to account for the temperature and the strain dependence of $\left| \overrightarrow{F_p} \right|$ by the introduction of several multiplicative terms in Equation (3):

$$\left| \overrightarrow{F_{p}}(B,T,\varepsilon) \right| = C \times \left(1 - a \times |\varepsilon - \varepsilon_{m}|^{1.7} \right)^{s} \times \left(\frac{B}{B_{c2}(\varepsilon,T)} \right)^{p} \times \left(1 - \frac{B}{B_{c2}(\varepsilon,T)} \right)^{q} \times \left(1 - \left(\frac{T}{T_{c}} \right)^{2} \right)^{\mu} \times \left(1 - \left(\frac{T}{T_{c}} \right)^{1.52} \right)^{\eta - \mu}$$
(5)

where *C*, *a*, μ , η , ε_m , *s*, and *T*_c are free-fitting parameters and $B_{c2}(\varepsilon, T)$ is given by a different function. On the one hand, Equation (5) is applicable only for Nb₃Sn and only at a moderate strain level [7–11]. On the other hand, the upgraded Equation (5) is a fitting function constructed in terms of the general flavor of the two-fluid model, where each new parameter is added to the equation through a multiplicative term of:

$$V(P) = V_0 \times \left(1 - \left(\frac{P}{P_{max}}\right)^m\right)^n,\tag{6}$$

where V(P) is the fitted value with a new variable; P, V_0 , P_{max} , m, and n are free-fitting parameters; and P_{max} is a maximal value for the new parameter (it is chosen within a given model; for instance, temperature dependences of the superconducting parameters are generally utilized $P_{max} = T_c$, which is the maximum temperature at which the superconducting state does exist).

In this regard, there is another often chosen form for the new fitting term based on an exponential function [12], from which we can mention the scaling law proposed by Fietz et al. [13] for Nb-Zr superconductors:

$$J_c(B,T) = a_0 \times exp^{-(\frac{B}{B_0})} + C_0,$$
(7)

where a_0 , B_0 , and C_0 are free-fitting parameters of the model. The temperature-dependent fitting term also can be represented by an exponential function, as it was proposed for the second-generation high-temperature superconducting wires (2G-wires) by Senatore et al. [14]:

$$J_{c}(B,T) = J_{c}(B=0,T=0) \times exp^{-(\frac{1}{T^{*}})} \times B^{-\alpha},$$
(8)

where $J_c(B = 0, T = 0)$, T^* and α are free-fitting parameters ($0.2 \le \alpha \le 0.9$ [14]).

It should be noted that Equation (8) is internally incorrect because the units of the right hand of the equation are not A/m^2 (which are the current density units). This mistake is becoming widely spread because, recently, Francis et al. [15] utilized Equation (8) (which is Equation (1) in [15]) for the analysis of nanostructured coated conductors too.

Overall, for MgB₂, cuprates, and iron-based superconductors (IBS), different expressions for $\left| \vec{F_p}(B) \right|$ were proposed [6,12–21] (extended review for REBCO given by Jirsa et al. [6]). For these compounds, due to their anisotropic nature, all free-fitting parameters of Equations (3) and (4) are angularly dependent. Additionally, due to the relatively wide transition width in these compounds, the primary ratio $\left(\frac{B}{B_{c2}} \right)$ in scaling laws (Equations (3) and (4)) is often replaced by $\left(\frac{B}{B_{irr}(\theta)} \right)$, where $B_{irr}(\theta)$ is the irreversibility field. Despite some differences, a primary assumption of all known scaling laws [3–21] is that $\left| \vec{F_p} \right|$ should have the applied magnetic field, *B*, as a primary variable (Equations (1)–(5)). Thus, all known scaling laws have been developed for $\left| \vec{F_p}(B) \right|$ values.

In this paper, we pointed out that $\left| \overrightarrow{F_p} \right|$ (Equation (1)) is also a function of J_c . This fact was, somehow, never considered. Thus, the $\left| \overrightarrow{F_p}(J_c) \right|$ scaling law should also exist. Based on this primary idea, we consider the full $\left| \overrightarrow{F_p}(J_c, B) \right|$ function and propose potential scaling laws for $\left| \overrightarrow{F_p}(J_c) \right|$ in thin film superconductors, which reflect different pinning characteristics of the materials. We limited our paper to the case when an external magnetic field, B, is applied, in the perpendicular direction, to the film's large surface, that is, for the field angle $\theta = 0^{\circ}$ [22].

2. Problem Description

A fundamental problem for an existing approach to scale $\left|\vec{F_{p}}\right|$ as a sole function of the applied magnetic field, *B*, which we found in this paper, is shown in Figure 1, where the $\left|\vec{F_{p}}(J_{c}, B, T = 4.2 \text{ K})\right|$ curve for a MgB₂ thin film is shown. It should be noted that raw $J_{c}(B, T, \theta = 0^{\circ})$ data for these films were reported by Zheng et al. [23], and the $J_{c}(B, T = 4.2 \text{ K}, \theta = 0^{\circ})$ dataset is shown in Figure 2a. Additionally, it needs to be mentioned that in all 3D representations of $\left|\vec{F_{p}}(J_{c}, B)\right|$, we used the same axis arrangement, where *X*-axis is J_{c} , *Y*-axis is *B*, and *Z*-axis is $\left|\vec{F_{p}}(J_{c}, B)\right|$.



Figure 1. Three-dimensional (3D) representation of the pinning force density, $\left| \vec{F_p}(J_c, B, T = 4.2 \text{ K}) \right|$, for a MgB₂ thin film. Raw $J_c(B, T = 4.2 \text{ K})$ data were reported by Zheng et al. [23].

It can be seen in Figure 1 that the $\left|\vec{F_p}(B)\right|$ curve (green), which is traditionally used for the pinning force analysis, represents a projection of the 3D $\left|\vec{F_p}(J_c, B)\right|$ curve (red) onto the X = 0 plane.

It should be stressed that at a low magnetic field, $B \leq \frac{1}{4}B_{c2}$, the entire $\left|\vec{F_p}(J_c, B)\right|$ curve (red) is directed nearly in the perpendicular direction to the X = 0 plane. For this reason, the projection (green curve) of this part of the $\left|\vec{F_p}(J_c, B)\right|$ curve onto the X = 0 plane cannot be considered a correct representation of the entire pinning force density $\left|\vec{F_p}(J_c, B)\right|$ curve.

This is the primary reason for the widely accepted deduction [6–21,24,25] of the *p*-parameter of Equation (3), which is the primary value in Kramer–Dew–Hughes scaling laws [2,3] at $\frac{B}{B_{c2}} \leq \frac{1}{4}$:

$$\left|\vec{F_p}(B)\right|_{B \lesssim \frac{1}{4}B_{c2}} = F_{p,max} \times \left(\frac{B}{B_{c2}}\right)^p \times \left(1 - \frac{B}{B_{c2}}\right)^q \Big|_{B \lesssim \frac{1}{4}B_{c2}} \to F_{p,max} \times \left(\frac{B}{B_{c2}}\right)^p, \quad (9)$$

cannot be considered to exhibit a sustainable meaning.



Figure 2. Projections of the $\left| \overrightarrow{F_p}(J_c, B, T = 4.2 \text{ K}, \theta = 0^\circ) \right|$ curve for a MgB₂ thin film into three orthogonal planes. Data fit for (**b**,**c**) panels are shown. (**a**) The projection into the $F_p = 0$ plane; (**b**) the projection into the $J_c = 0$ plane and data fit to Kramer–Dew–Hughes (Equation (3)); and (**c**) the projection into the B = 0 plane and data fit to a linear piecewise model (Equation (13)) (the cyan ball at the origin indicates $\left| \overrightarrow{F_p}(J_c) \right|$ at $B = B_{c2}$); (**d**) the projection into the $F_p = 0$ plane, where two overlapped branches are shown (see details in the text). Raw $J_c(B, T = 4.2 \text{ K}, \theta = 0^\circ)$ data were reported by Zheng et al. [23]. Shown by shadow areas are 95% confidence bands.

The geometrical representation shown in Figure 1 (where the pinning force density line is directed in a nearly orthogonal direction to the X = 0 plane) also explains why Equation (9) cannot be used to extract $J_c(B)$ at a low applied magnetic field, as well the self-field critical current density, $J_c(B = sf)$ (when the applied magnetic field is B = 0 T), from the pinning force density:

$$\left|\vec{F_p}(B)\right|_{B \lesssim \frac{1}{4}B_{c2}} \cong F_{p,max} \times \left(\frac{B}{B_{c2}}\right)^p = J_c \times B,\tag{10}$$

$$J_c\left(B \lesssim \frac{1}{4}B_{c2}\right) = \frac{F_{p,max}}{\left(B_{c2}\right)^p} \times \frac{1}{B^{1-p}},\tag{11}$$

where p < 1, and thus:

$$\lim_{B \to 0} J_c(B) = \infty, \tag{12}$$

which contradicts with experimental observations.

It should be also mentioned that the existing theory of Abrikosov's flux pinning [5] can be used to derive solid theoretical values for the *p*-parameter in Equation (3) for certain types of pinning mechanisms, defect dimensionality, vortex pinning length, and so on

(see, for instance, [5]). However, it can be seen from all of the above that this parameter cannot be accepted to be a sustainable value that characterizes the pinning force density (Equation (1)) in superconductors.

To demonstrate that the $\left|\vec{F_p}(B, J_c)\right|$ dataset for the MgB₂ thin film (shown in Figure 1) represents a typical dataset for superconducting films, we fitted the projection of this dataset into the X = 0 plane, that is, $\left|\vec{F_p}(B)\right|$, to Equation (3) in Figure 2b. The deduced parameters $p = 0.45 \pm 0.03 \approx 0.5$ and $q = 2.3 \pm 0.5 \approx 2$ certainly represent typical characteristic values that are often deduced from the $\left|\vec{F_p}(B)\right|$ fits to Equation (3) [11,25,26].

It is crucial to note that this set of parameters, p = 0.5 and q = 2, was listed by Dew-Hughes in his table ([5]), and this set of parameters implies that the flux pinning is due to the grain boundary pinning [5]. However, films fabricated by Zheng et al. [23] are epitaxial films on single crystal substrates, and thus, there is no expectation that grain boundaries are exhibited in these MgB₂ thin films. However, as it is mentioned in [23], the critical current density in the MgB₂ film can be governed by the grain boundaries formed by local nonstoichiometry/secondary phases, and these fine structures can act as grain boundary pinning centers at a low applied magnetic field.

Considering another projection of the 3D $\left| \vec{F_p}(J_c, B) \right|$ curve into the Z = 0 plane, which is $J_c(B)$ (royal curve in Figures 1 and 2a), we should mention that $J_c(B)$ is largely distant from the $\left| \vec{F_p}(J_c, B) \right|$ curve, except the two points of $J_c(B = 0)$ and of $J_c(B = B_{c2})$, where the $\left| \vec{F_p}(J_c, B) \right|$ curve intersects the plane (Figure 1). This implies that the $J_c(B)$ projection represents the most distorted projection of the 3D $\left| \vec{F_p}(J_c, B) \right|$ curve from three orthogonal projections of this curve. Thus, if one assumes that the primary idea expressed by Anderson [1,2] is correct (i.e., that Equation (1) describes the upper limit for the dissipative-free transport current flow), then the use of the $J_c(B)$ curve for the analysis of pinning properties of materials represents the most inappropriate choice of raw experimental data for the analysis.

Two projections of the 3D $\left|\vec{F_p}(J_c, B)\right|$ curve (i.e., $\left|\vec{F_p}(B)\right|$ and $J_c(B)$) are in a wide use to characterize superconducting materials, and the third projection, $\left|\vec{F_p}(J_c)\right|$ (magenta curve in Figures 1 and 2c), from the best author's knowledge is introduced herein. $\left|\vec{F_p}(J_c)\right|$ exhibits a nearly linear dependence on both sides from the $F_{p,max}(J_c)$ point (Figures 1 and 2c). Based on this $F_{p}(J_{c})$ for this MgBa thin film can be approximated by a piecewise function of two

on this, $F_p(J_c)$ for this MgB₂ thin film can be approximated by a piecewise function of two linear functions:

$$F_p(J_c) = \theta(J_c \le J_{c,Fp,max}) \times (c_1 \times J_c + f_1) + \theta(J_c \ge J_{c,Fp,max}) \times (c_2 \times J_c + f_2),$$
(13)

where c_1 , f_1 , c_2 , and f_2 are free-fitting parameters and $\theta(x)$ is the Heaviside function. The fit of $F_p(J_c)$ to Equation (13) is shown in Figure 2c. Based on the deduced ratio of Figure 2c:

$$\frac{J_{c,Fp,max}}{J_c(sf)} = 0.03,$$
 (14)

one can conclude a nearly full $F_p(J_c)$ dependence; that is, the range is:

$$0.03 \times J_c(sf) \le J_c \le J_c(sf),\tag{15}$$

which can be approximated by a simple linear equation:

$$F_p(J_c) \equiv J_c(B) \times B = (c_2 \times J_c(B) + f_2), \tag{16}$$

$$J_c(B) = \frac{f_2}{B - c_2} = \frac{f_2}{B + |c_2|} = \frac{\frac{f_2}{|c_2|}}{1 + \frac{B}{|c_2|}} = \frac{J_c(B = 0)}{1 + \frac{B}{|c_2|}},$$
(17)

Surprisingly enough, Equation (17) is a well-known Kim model equation [27,28]. Our derivation is solely based on a 3D graphical representation of the $\left|\vec{F}_{p}(J_{c}, B)\right|$ dataset

(Figure 1).

To answer the question what is the physical meaning of the t $|c_2|$ parameter in Equation (17), we first should mention that this parameter has the unit of magnetic flux density (i.e., Tesla), and that this parameter is neither B_{c2} nor B_{irr} , because its absolute value for the MgB₂ film is $|c_2(T = 4.2 \text{ K})| = 88 \pm 5 \text{ mT}$ (Figure 2), which is about two orders of magnitude below the upper critical field value. However, the latter value, which can be called the pinning field, $|c_2(T)|$, is comparable with $B_{c1}(T = 4.2 \text{ K})$ (see, for instance, [29–32]), which indicates that $|c_2(T)|$ is related to the low- and middle-field part of the $|\vec{F_p}(J_c, B)|$ curve.

Considering that $B_{c1}(T)$ is the magnetic field at which Abrikosov's vortices have thermodynamic preference to exhibit in the superconductor, it is useful to quantify the deduced pinning field, $|c_2(T)|$, vs. the fundamental lower critical field of the material (at low- and middle-ranges of the applied magnetic field) by a factor of $|c_2(T)|$ enhancement over $B_{c1}(T)$:

$$c = \frac{|c_2(T)|}{B_{c1}(T)},$$
(18)

Considering that the lower critical field is given by [33]:

$$B_{c1}(T) = \frac{\phi_0}{4\pi} \times \frac{\ln\left(1 + \sqrt{2}\kappa(T)\right)}{\lambda^2(T)},\tag{19}$$

and the self-field critical current density [34]:

$$J_c(B=0) = \frac{\phi_0}{4\pi\mu_0} \times \frac{\ln\left(1+\sqrt{2}\kappa(T)\right)}{\lambda^3(T)},\tag{20}$$

one can calculate the lower limit of the pinning force density, $F_{p,lower \ limit}(T)$, which can be achievable in the pinning-free thin film:

$$B_{c1}(T) = \left[\frac{\phi_0}{4\pi} \times \ln\left(1 + \sqrt{2} \times \kappa(T)\right)\right]^{\frac{1}{3}} \times (\mu_0 \times J_c(sf,T))^{\frac{2}{3}}.$$
 (21)

Utilizing the reported $J_c(B = 0, T = 4.2 \text{ K}) = 35 \text{ MA/cm}^2$ [20] and $\kappa(T) = 26$ [35], one can calculate $B_{c1}(T = 4.2 \text{ K}) = 49 \text{ mT}$, which implies that the pinning field can be characterized by the enhancement factor $\varepsilon(T = 4.2 \text{ K}) = 1.8$. We should be clear that the applied magnetic field, for which the $|c_2(T = 4.2 \text{ K})| = 0.088 \pm 0.005 T$ field was deduced, covers a wide range:

$$5 \times 10^{-4} \text{ T} \le B \le 1.0 \text{ T}$$
 (22)

and the deduced values (i.e., $|c_2|$ and ε) characterize the pinning properties of the given MgB₂ film within a wide range of the applied magnetic field (i.e., low and middle applied field ranges).

From the conceptual point of view, the $|c_2(T)|$ field can be interpreted as the so-called matching field, which is defined as the field at which each defect in the material holds

one Abrikosov's vortex. Despite intensive attempts (which were mainly focused on heavy ion irradiation of cuprates, where ion damaging tracks can be prepared in the form of continuous lines and, thus, the matching field can be calculated) [36–38], the matching field has been never reliably extracted from experimental $J_c(B,T)$ data.

If this interpretation is correct, then it can be useful to introduce a characteristic hexagonal lattice parameter, $d_{hexagonal}(T)$, between Abrikosov's vortices, which corresponds to the $|c_2|$ field in the assumption of hexagonal vortices' lattice [39]:

$$d_{hexagonal}(T) = \left(\frac{\phi_0}{\frac{1}{2}\sqrt{3}|c_2(T)|}\right)^{\frac{1}{2}}.$$
(23)

For the given MgB₂ film, the equivalent lattice parameter is $d_{hexagonal}(T = 4.2 \text{ K}) = 165 \text{ nm}$, which indicates that this film is nearly pinning-site-free.

At a high applied magnetic field range, the $\left|\vec{F_p}(J_c, B)\right|$ curve (red) is directed nearly in the perpendicular direction to the Y = 0 plane. For this reason, the projection (magenta curve) of this part of the $\left|\vec{F_p}(J_c, B)\right|$ curve into the Y = 0 plane cannot be considered accurate approximation for the 3D pinning force density $\left|\vec{F_p}(J_c, B)\right|$ curve.

However, an essential difference of the $\left|\vec{F_p}(J_c)\right|$ projection from its orthogonal counterparts and the 3D $\left|\vec{F_p}(J_c, B)\right|$ curve itself is that the $\left|\vec{F_p}(J_c)\right|$ dataset always includes the origin point in the total dataset. Truly, by the definition, $\left|\vec{F_p}(J_c, B)\right| = 0$ at $J_c = 0$ at any $B = B_{c2}$ (even for the case when the B_{c2} value is unknown). In Figure 2c, this origin point is depicted by the cyan color.

Overall, Figure 1 shows that the 3D $\left|\vec{F_p}(J_c, B)\right|$ curve at a low applied magnetic field is better approximated by the $\left|\vec{F_p}(J_c)\right|$ projection, while at a high applied magnetic field, the curve is better approximated by $\left|\vec{F_p}(B)\right|$. These two curves are overlapped at some middle range of the applied magnetic field. The limiting values for the overlapping range can be chosen to correspond to the field values at $\left|\vec{F}_{p,max}(B)\right|$ and $\left|\vec{F}_{p,max}(J_c)\right|$, shown in Figure 2d.

Thus, we can propose to split a $\left| \overrightarrow{F_p}(J_c, B) \right|$ curve in three distinctive ranges:

- 1. Low reduced applied magnetic field range, where $\left|\vec{F_p}(J_c, B)\right|$ can be approximated by the $\left|\vec{F_p}(J_c)\right|$ projection;
- 2. High reduced applied magnetic field range, where $\left|\vec{F_p}(J_c, B)\right|$ can be approximated by the $\left|\vec{F_p}(B)\right|$ projection;
- 3. Middle reduced applied magnetic field, where $\left|\vec{F_p}(J_c)\right|$ and $\left|\vec{F_p}(B)\right|$ branches are overlapped and an approximation can be achieved by constructing some new function, where both branches are presented with some weights.

In next sections, we show the usefulness of this approach to analyze $|\vec{F_p}(J_c, B)|$ data for thin films of MgB₂, NdFeAs(O,F), REBCO, and near-room-temperature superconducting superhydrides (La,Y)H₁₀ and YH₆. It should be mentioned that we considered only transport current datasets to avoid additional complication with the conversion of the magnetization data into the critical current density.

3. Results

$3.1. MgB_2$

The pinning force density $\left|\vec{F_p}(B,T)\right|$ in pure and doped MgB₂ films is studied in detail [40–42]. Here, we chose for the analysis the $\left|\vec{F_p}(B, J_c, T)\right|$ dataset reported by Zheng et al. [23], who fabricated high-quality MgB₂ films by hybrid physical-chemical vapor deposition on two types of silicon carbide single-crystal substrates (4H-SiC and 6H-SiC) and reported transport $J_c(B,T)$ datasets for the film deposited on a 6H-SiC substrate. The $\left|\vec{F_p}(J_c, B, T = 4.2 \text{ K})\right|$ dataset was already analyzed in Figures 1 and 2. In Figure 3 $\left|\vec{F_p}(J_c, B, T)\right|$ datasets measured at different temperatures are shown together with fits to Equation (13).



Figure 3. $\left|\vec{F_p}(J_c, T, \theta = 0^\circ)\right|$ curves and data fits to Equation (13) for a MgB₂ thin film deposited on a 6H-SiC single-crystal substrate for the temperature range of 4.2–30 K (**a**–**f**). Raw transport $J_c(B, T, \theta = 0^\circ)$ data were reported by Zheng et al. [23]. The goodness of fit for all panels is better than R = 0.985. Shown by shadow areas are 95% confidence bands.

There are three findings revealed by the $\left| \overrightarrow{F_p}(J_c) \right|$ data fits to Equation (13):

- 1. A linear dependence of $|F_p(J_c)|$ vs. J_c remains at all temperatures (Figure 3).
- 2. The J_c range, where this linear dependence exhibits, covers a nearly full J_c range:

$$0.04 \times J_c(sf, T) \le J_c(B, T) \le J_c(sf, T).$$
 (24)

3. The pinning field enhancement factor, $\varepsilon(T)$ (Equation (18)), remains nearly the same for a full temperature range (Figure 4):

$$1.45 \le \varepsilon(T) \le 1.80 \text{ (for } 4.2 \text{ K} \le T \le 35 \text{ K)}.$$
 (25)

This implies that the characteristic field, $|c_2(T)|$ (Equation (13)), for the MgB₂ film can be approximately scaled as the lower critical field, $B_{c1}(T)$, for this material.



Figure 4. (a) Deduced free-fitting parameter $|c_2(T)|$ (Equation (13)) and $B_{c1}(T)$ calculated by Equation (21) for a MgB₂ thin film deposited on a 6H-SiC single-crystal substrate for which raw transport $J_c(B, T, \theta = 0^\circ)$ data were reported by Zheng et al. [23]. (b) The pinning field enhancement factor $\varepsilon(T)$ (Equation (18)) for the MgB₂ film. (c) Equivalent hexagonal lattice parameter $d_{hexagonal}(T)$ (Equation (23)) for the MgB₂ film.

The $|\vec{F_p}(B,T)|$ data fits to Equation (3) and deduced parameters are shown in Figures 5 and 6, respectively. It can be seen (Figure 6) that both deduced parameters, p(T) and q(T), are varying within very wide ranges, which were not described by Dew-Hughes [5]. Moreover, the p(T) and of q(T) parameters deduced at different temperatures indicate different pinning mechanisms. For instance, p(T = 25 K) = 0.36 and q(T = 25 K) = 1.1, which imply that the pinning is due to magnetic/volume/normal mechanism [5], while p(T = 10 K) = 0.4 and q(T = 10 K) = 1.9, which imply that the pinning is due to the core/surface/normal mechanism [5]. This result demonstrates that the Kramer–Dew–Hughes [4,5] model exhibits a problem with the validity of deduced value



interpretation, while mathematical fits to Equation (3) are, as a rule, reasonably accurate approximated $\left| \overrightarrow{F_{p}}(B) \right|$ data.

Figure 5. $\left|\vec{F_p}(B, T, \theta = 0^\circ)\right|$ curves and data fits to Equation (13) for a MgB₂ thin film deposited on a 6H-SiC single-crystal substrate for the temperature range of 4.2–30 K (**a**–**f**). Raw transport $J_c(B, T, \theta = 0^\circ)$ data were reported by Zheng et al. [23]. The goodness of fit for all panels is better than R = 0.995. Shown by shadow areas are 95% confidence bands.



Figure 6. Deduced free-fitting parameters p(T) (**a**) and q(T) (**b**) of the Kramer–Dew–Hughes model (Equation (5)) for a MgB₂ thin film deposited on a 6H-SiC single-crystal substrate for which raw transport $J_c(B, T, \theta = 0^\circ)$ data were reported by Zheng et al. [23].

3.2. Pnictide Thin Films

In this section, the analysis was applied for two NdFeAs(O,F) thin films for which raw transport critical current density data, $J_c(B, T, \theta = 0^\circ)$, were reported by Tarantini et al. [43] and Guo et al. [44]. Both research groups found that the $\left|\vec{F_p}(B, T, \theta = 0^\circ)\right|$ data fit to Equation (3) generates unphysical p(T) and q(T) values, which was interpreted as a demonstration of a superposition of two different pinning mechanisms. To resolve this problem, Tarantini et al. [43] proposed to fit $\left|\vec{F_p}(B, T, \theta = 0^\circ)\right|$ datasets to a function that is a sum of two Kramer–Dew–Hughes functions, where one function accumulates the contribution of the surface pinning (for which $p(T) \equiv 0.5$ and $q(T) \equiv 2.0$ in accordance with 5) and another function accumulates the contribution of the point pinning (for which $p(T) \equiv 1.0$ and $q(T) \equiv 2.0$ in accordance with [5]):

$$\left|\vec{F_p}(B)\right| = F_{p,max,s} \times \left(\frac{B}{B_{irr,s}}\right)^{0.5} \times \left(1 - \frac{B}{B_{irr,s}}\right)^2 + F_{p,max,pd} \times \left(\frac{B}{B_{irr,pd}}\right)^{1.0} \times \left(1 - \frac{B}{B_{irr,pd}}\right)^2.$$
(26)

A slightly different approach was proposed by Guo et al. [44], who considered that two summation parts in Equation (26) have $q(T) \equiv 2.0$, and thus, these authors proposed to use the following fitting function:

$$\left|\vec{F_p}(B)\right| = F_{p,max} \times \left(\frac{B}{B_{irr}}\right)^p \times \left(1 - \frac{B}{B_{irr}}\right)^2 \tag{27}$$

where *p* is free-fitting parameter. Because the surface pinning is characterized by $p \equiv 0.5$ and the point pinning is characterized by $p \equiv 1.0$ [5], the proximity of the free-fitted *p*-value to either 0.5 or 1.0 can be interpreted as the dominance of the surface pinning or the point pinning.

In the results, both research groups [43,44] reported that the point pinning dominates at $0.5 \leq \frac{T}{T_c}$, while at $\frac{T}{T_c} \leq 0.5$, the dominant mechanism is the surface pinning. Because the comprehensive analysis of $\left|\vec{F_p}(B, T, \theta = 0^\circ)\right|$ for NdFeAs(O,F) thin films was reported in [42,44], here we are apply presented on an elemin for the $\left|\vec{F_p}(B, T, \theta = 0^\circ)\right|$ detects

in [43,44], here, we only presented an analysis for the $\left|\vec{F_p}(J_c, T, \theta = 0^\circ)\right|$ datasets.

In Figure 7, we show the $\left| \overrightarrow{F_p}(J_c, B, T = 35 \text{ K}, \theta = 0^\circ) \right|$ dataset for the NdFeAs(O,F) thin film for which $J_c(B, T, \theta = 0^\circ)$ was reported by Guo et al. [44].

A $|\vec{F_p}(B)|$ curve (green) can be fitted to Equation (26) with high quality (Figure 8). However, on this projection, an important property of the $\left|\vec{F_p}(J_c, B, T = 35 \text{ K})\right|$ dataset, which is a linear dependence of $\left|\vec{F_p}(J_c, B, T = 35 \text{ K})\right|$ vs. J_c (Figures 7 and 8c), is invisible.

Another important feature, which makes the $|\vec{F_p}(J_c, B, T)|$ curve for the NdFeAs(O,F) thin film different from its counterpart for the MgB₂ film (Figures 1 and 2), is that the low-field linear part of the $|\vec{F_p}(J_c, B, T)|$ curve abruptly transforms into a domelike shape of $|\vec{F_p}(J_c, B, T)|$ at the $J_{c,Fp,switch}$ point. This important feature is also invisible in the $|\vec{F_p}(B)|$ projection of the $|\vec{F_p}(J_c, B, T)|$ curve (Figure 8b).



Figure 7. Three-dimensional (3D) representation of the pinning force density, $\left|\vec{F}_{p}(J_{c}, B, T = 35 \text{ K}, \theta = 0^{\circ})\right|$, NdFeAs(O,F) thin film for which $J_{c}(B, T, \theta = 0^{\circ})$ was reported by Guo et al. [44].



Figure 8. Projections of the $\left|\vec{F}_{p}(J_{c}, B, T = 35 \text{ K}, \theta = 0^{\circ})\right|$ curve for the NdFeAs(O,F) thin film into three orthogonal planes. Data fits to the Equation (27) panel (**b**) and Equation (30) panel (**c**) are shown.

(a) The projection into the $F_p = 0$ plane; (b) the projection into the $J_c = 0$ plane and data fit to Kramer–Dew–Hughes (Equation (3)); and (c) the projection into the B = 0 plane and data fit to a piecewise model (Equation (28)). Deduced parameters are: $\frac{J_{c,Fp,max}}{J_c(sf)} = 0.23$, $\frac{J_{c,Fp,switch}}{J_c(sf)} = 0.53$, $J_{c,Fp,max} = 0.07 \frac{MA}{cm^2}$, $J_{c,Fp,switch} = 0.18 \frac{MA}{cm^2}$, and $J_c(sf) = 0.32 \frac{MA}{cm^2}$. Numbers a, b, and c in panel c with respect to the schematic representation of the vortex lattice structure shown in Figure 9. Raw $J_c(B, T = 35 \text{ K}, \theta = 0^\circ)$ data were reported by Guo et al. [44]. Shown by shadow areas are 95% confidence bands.



Figure 9. Schematic representation of the vortex structure when the magnetic field is applied in the perpendicular direction to the thin film surface. (a) The vortex structure at a low applied magnetic field, $B < |c_2|$, which corresponds to the linear part (marked as "1" in Figure 8c) of the $\left| \overrightarrow{F_p}(J_c) \right|$ pinning force density. The distance between vortices, $d_{hexagonal}$, corresponds to the $|c_2|$ field (Equation (23). (b) The vortex structure at the applied field $B \cong B_{switch} \cong |c_2|$ (this stage is depicted by arrows "2" and $F_{p,switch}(J_c)$ in Figure 8c. (c) The vortex structure at the applied field $B > |c_2|$ when the material exhibits a collective flux pinning effect. This stage is schematically shown by arrow "3" in Figure 8c.

One can see in Figures 7 and 8 that the 3D $\left| \vec{F_p}(J_c, B, T) \right|$ curve starts to deviate from the $\left| \vec{F_p}(J_c, T) \right|$ projection when $J_c \leq J_{c,Fp,switch}$. For $J_c \leq J_{c,Fp,max}$, the 3D $\left| \vec{F_p}(J_c, B, T) \right|$ curve is better approximated by the $\left| \vec{F_p}(B, T) \right|$ projection. The fitting function for the domelike part of the $\left| \vec{F_p}(J_c, T) \right|$ curve should be flexible within the full range of $J_c \leq J_{c,Fp,switch}$.

We constructed several possible functions and found that the general form proposed by Kramer [4] and by Dew-Hughes [5] can reasonably well fit $\left|\vec{F_p}(J_c, T)\right|$ data:

$$F_{p}(J_{c}) = \theta \left(J_{c} \leq J_{c,Fp,switch} \right) \left(\frac{J_{c}}{J_{c,1}} \right)^{l} \left(1 - \left(\frac{J_{c}}{J_{c,1}} \right) \right)^{m} + \theta \left(J_{c} \geq J_{c,Fp,switch} \right) (c_{2} \times J_{c} + f_{2})$$

$$(28)$$

where $J_{c,Fp,switch}$, $J_{c,1}$, l, m, c_2 , and f_2 are free-fitting parameters. It should be stressed that because (as one can see in Figures 1 and 7) the projection of the 3D $\left|\vec{F_p}(J_c, B, T)\right|$ curve into the B = 0 plane is significantly distorted from its original 3D curve, when $0 \le J_c \le J_{c,Fp,max}$. Additionally, the fit to Equation (28) can be a good approximation for J_c values within the range of $J_{c,Fp,max} \le J_c \le J_c(sf)$.

Thus, there is an interesting analogy with the Kramer–Dew–Hughes fit (Equation (3)), which is a reasonably accurate approximation for the $\left|\overrightarrow{F_p}(J_c, B, T)\right|$ curve for large applied magnetic fields, that is, within a range of $B_{Fp,max} \leq B \leq B_{c2}$, while Equation (28) is a good approximation for $\left|\overrightarrow{F_p}(J_c, B, T)\right|$ for large critical current densities, $J_{c,Fp,max} \leq J_c \leq J_c(sf)$, or what is the equivalent statement, for low- and middle-range applied magnetic fields $0 \leq B \leq B_{Fp,max}$.

However, we can note that Equation (28) has a linear part, which represents a significant difference between Equations (3) and (28). In addition, as we stated above, there is a need to revise the validity of the primary interpretation of the p and q parameters in the Kramer–Dew–Hughes fit, which was proposed by Dew-Hughes nearly five decades ago [5]. Based on this concern, we do not provide any interpretation for the l and m parameters in Equation (28) now.

To interpret the physical origin of the appearance of the domelike bump in the $\left|\vec{F}_{p}(J_{c},T)\right|$ datasets (Figure 9), which suddenly appeared at $J_{c} \leq J_{c,Fp,switch}$ (Figure 8c), we can propose that this dome is due to the effect of Abrikosov's vortices' collective pinning [45]. This effect was theoretically predicted by Larkin and Ovchinnikov more than five decades ago [45], and despite a wide discussion of this effect in cuprates [46], to the author's best knowledge, Figure 8 represents clear experimental evidence for the existence of this effect. This interpretation is well aligned with the absence of the collective pinning in

MgB₂, and thus, Figures 1–3 demonstrate that the domelike bump in the $|F_p(J_c, T)|$ datasets does not exist.

Following a general idea for the magnetic flux distribution in a thin superconducting slab when the external magnetic field is applied in the perpendicular direction to the film surface proposed by Brandt and Indenbom [47], in Figure 9, we show a schematic representation for vortices' lattice for three distinguishing parts of the $\left|\vec{F_p}(J_c)\right|$ curve, which can be seen in Figure 8c. At a low applied magnetic field, that is, $B < |c_2|$, Abrikosov's vortices fill the superconducting film starting from the slab edges and vortices separated by the distance, $d_{hexagonal}$, which corresponds to the $|c_2|$ field (Equation (23)). This stage corresponds to the linear part of the $\left|\vec{F_p}(J_c)\right|$ curve indicated by the letter "a" in Figure 8c.

The vortices completely and uniformly fill the film at the applied field of $B \cong B_{switch} \cong |c_2|$, while the distance between vortices remains to be $d_{hexagonal}$ (Equation (23)). This stage is indicated by the letter "b" in Figure 8, and the schematic diagram is shown in Figure 9b.

At the applied $B > |c_2|$, there are two possible scenarios. One is for materials such as MgB₂, which do not exhibit the collective flux pinning effect, and after the applied field reaches $|c_2|$, the pinning force density is rapidly dropped (see, for instance, Figure 3).

Otherwise, if a material exhibits the collective flux pinning effect, Abrikosov's vortices penetrate in the slab from the edges and form the second flux penetration front, which has a much higher fluxon density and does not exhibit a hexagonal flux lattice structure.

The fit of the $\left|\vec{F_p}(J_c, T = 35 \text{ K})\right|$ dataset to Equation (28) and calculations based on Equations (18), (21) and (23) reveal the following values (for calculations, we used the Ginzburg–Landau parameter $\kappa(T) = 90$ [48]):

$$|c_2(T = 35 \text{ K})| = 0.38 \pm 0.02 \text{ T}$$
 (29)

$$B_{c1}(T = 35 \text{ K}) = 2.3 \times 10^{-3} \text{ T}$$
 (30)

$$\varepsilon(T = 35 \text{ K}) = 16.5$$
 (31)

$$d_{hexagonal}(T = 35 \text{ K}) = 79 \text{ nm}$$
(32)

Fits to Equation (28) of $\left| \vec{F_p}(J_c, T) \right|$ datasets measured at different temperatures for the NdFeAs(O,F) thin film are shown in Figures 10 and 11.



Figure 10. $\left| \overrightarrow{F_p}(J_c, T, \theta = 0^\circ) \right|$ curves and data fits to Equation (28) for the NdFeAs(O,F) thin film measured in the temperature range of 4.2–30 K (**a**–**f**). Raw transport $J_c(B, T, \theta = 0^\circ)$ data were reported by Guo et al. [44]. The goodness of fit for all panels is better than R = 0.998. Shown by shadow areas are 95% confidence bands.



Figure 11. $|\vec{F_p}(J_c, T, \theta = 0^\circ)|$ curves and data fits to Equation (28) for the NdFeAs(O,F) thin film measured at temperature (**a**) 35 K; (**b**) 38 K; (**c**) 41 K. Raw transport $J_c(B, T, \theta = 0^\circ)$ data were reported by Guo et al. [44]. The goodness of fit for all panels is better than R = 0.998. Shown by shadow areas are 95% confidence bands.

Overall, $|\vec{F_p}(J_c, T)|$ datasets measured at high reduced temperatures, $\frac{T}{T_c}$, have a very pronounced linear part (Figure 11). When the datasets do not contain large-enough raw data points to be fitted to Equation (28) (for all parameters are free), we fix the m = 2.0 value, adopting the approach proposed for NdFeAs(O,F) thin films in [38,39]. The primary reason for this is that our purpose is to extract as accurately as possible the $|c_2(T)|$ value, which is the $F_p(J_c)$ slope at a low applied magnetic field. Based on this, the accuracy of the approximation of the collective pinning peak in $F_p(J_c)$ cannot be characterized as our primary task, because we target to deduce the values listed in Equations (29)–(32), for which parameters describing the collective pinning bump are not required.

It is important to note that all fits to Equation (28) of all reported (by Guo et al. [44]) $F_p(J_c)$ datasets were converged, which is a prominent advantage versus $F_p(B)$ datasets fit to Equation (5), where the converging is the main issue, especially for datasets measured at low temperatures.

The converged $F_p(J_c)$ curve can be inverted to calculate the important pinning parameter $B_{Fp,max}$, which cannot be extracted from $F_p(B)$ datasets, because the latter dependences, as a rule, at $T \sim 4$ K for all practically important materials (i.e., cuprates and IBS) are an increasing function of *B*. Based on this, the $F_p(B, T = 4.2$ K) fits to Equation (3) diverge.

However, if the same $\left|\vec{F_p}(J_c, B, T = 4.2 \text{ K})\right|$ dataset is to be projected into the B = 0plane (which is $\left|\vec{F_p}(J_c, T = 4.2 \text{ K})\right|$), it can converge, as is demonstrated in Figure 10a. Because the $\left|\vec{F_p}(J_c, T = 4.2 \text{ K})\right|$ curve, as we mentioned above, is an accurate approximation for the 3D $\left|\vec{F_p}(J_c, B, T = 4.2 \text{ K})\right|$ curve for $0 \le B \le B_{Fp,max}$, the deduced $B_{Fp,max}(T = 4.2 \text{ K})$ from the converged fit to Equation (28) can be a reasonably accurate estimation for $B_{Fp,max}(T = 4.2 \text{ K})$. To perform this inversion of the fitted $\left| \vec{F_p}(J_c, T = 4.2 \text{ K}) \right|$ curve for the NdFeAs(O,F) film (Figure 10a), one obtains $B_{Fp,max}(T = 4.2 \text{ K}) = 21 \text{ T}$, which is significantly above the highest applied magnetic field in the given experiment, B = 14 T [44].

Primary deduced parameters are shown in Figure 12. There are remarkable high values for the pinning field enhancement factor, $\varepsilon(T)$, within a full temperature range. This is the most distinguished difference in values deduced for the NdFeAs(O,F) thin film in comparison with MgB₂ (see, for instance, Figures 4 and 12).



Figure 12. (a) Deduced free-fitting parameter $|c_2(T)|$ (Equation (13)) and $B_{c1}(T)$ calculated by Equation (21) for the NdFeAs(O,F) thin film for which raw transport $J_c(B, T, \theta = 0^\circ)$ data were reported by Guo et al. [44]. (b) The pinning field enhancement factor $\varepsilon(T)$ (Equation (18)) for the same film. (c) Equivalent hexagonal lattice parameter $d_{hexagonal}(T)$ (Equation (23)) for the same film.

3.3. REBCO Thin Films

The introduction of nanoscaled secondary phases (so-called artificial pinning centers (APC)) in REBCO thin films is a conventional approach to enhance the in-field critical current density, $J_c(B, T)$, which was introduced nearly simultaneously by MacMagnus-Driscoll et al. [49] and Haugan et al. [50]. However, there are a growing number of pieces of experimental evidence [22,51] that a prominent $J_c(B, T)$ enhancement exhibits only at a high reduced temperature range, that is, at $0.7 \leq \frac{T}{T_c}$, while at $\frac{T}{T_c} \leq 0.25$, the enhancement originated from APC and 124-stacking faults practically vanishes [22,51].

In attempts to develop a better understanding of this problem, which has a great practical importance [52], we analyzed $\left|\vec{F_p}(J_c, B, T)\right|$ data for REBCO thin films by the approach described above.

In Figure 13, we show a 3D $\left| \overrightarrow{F_p}(J_c, B, T = 75.5 \text{ K}) \right|$ data curve for an undoped YBa₂Cu₃O_{7- δ} thin film (Sample 87) reported by MacMagnus-Driscoll et al. [49] (it should be noted that in Figure 1b [49] (from which $J_c(B, T = 75.5 \text{ K})$ data were digitized), the *Y*-axis has a mistake in value numbering).



Figure 13. Three-dimensional (3D) representation of the pinning force density, $\left|\vec{F}_{p}(J_{c}, B, T = 75.5 \text{ K}, \theta = 0^{\circ})\right|$, for the undoped YBa₂Cu₃O_{7- δ} thin film (Sample 87 [49]). Raw $J_{c}(B, T = 75 \text{ K}, \theta = 0^{\circ})$ data were reported by MacMagnus-Driscoll et al. [49].

Three orthogonal projections of the $\left|\vec{F_p}(J_c, B, T = 75.5 \text{ K})\right|$ curve are shown in Figure 14, where one can see that the fit to Equation (3) of the $\left|\vec{F_p}(B)\right|$ dataset has a high quality. However, a linear dependence of $\left|\vec{F_p}(J_c, B, T = 75.5 \text{ K})\right|$ vs. J_c (Figures 13 and 14c,d), which covers a significant part of the $0.25 \leq \frac{J}{J_c(sf)} \leq 1.0$ range, cannot be recognized in the $\left|\vec{F_p}(B)\right|$ projection.

The fit of the $\left|\vec{F_p}(J_c, T = 75.5 \text{ K})\right|$ dataset to Equation (28) is shown in Figure 14c, where the *m* parameter was fixed to m = 2.0. However, a more accurate approximation of the linear part and the full $\left|\vec{F_p}(J_c, T = 75.5 \text{ K})\right|$ curve is achieved by using a three-step linear piecewise function:

$$F_{p}(J_{c}) = \theta(J_{c} \leq J_{c,Fp,max})(c_{0} \times J_{c} + f_{0}) + \theta(J_{c} \geq J_{c,Fp,max})\theta(J_{c} \leq J_{c,Fp,switch})(c_{1} \times J_{c} + f_{1}) + \theta(J_{c} \geq J_{c,Fp,switch})(c_{2} \times J_{c} + f_{2})$$
(33)

The fit is shown in Figure 14d.



Figure 14. Projections of the $\left|\vec{F_p}(J_c, B, T = 75.5 \text{ K}, \theta = 0^\circ)\right|$ curve for the YBa₂Cu₃O_{7- δ} thin film into three orthogonal planes. Raw $J_c(B, T = 75.5 \text{ K}, \theta = 0^\circ)$ data panel (**a**) and data fits to the Equation (3) panel (**b**), Equation (28) panel (**c**), and Equation (33) panel (**d**) are shown. (**a**) The projection into the $F_p = 0$ plane; (**b**) the projection into $J_c = 0$; (**c**,**d**) the projection into the B = 0 plane. For panel (**c**), the parameters in Equation (28) are $l = 0.73 \pm 0.2$ and m = 2.0 (fixed). The goodness of fit is R = 0.988. For panel (**d**), the goodness of fit is R = 0.985. Raw $J_c(B, T = 75.5 \text{ K}, \theta = 0^\circ)$ data were reported by MacMagnus-Driscoll et al. [49]. Shown by shadow areas are 95% confidence bands.

Equation (33) represents one of the simplest and, simultaneously, remarkably accurate mathematical expressions of our primary idea that $\left| \overrightarrow{F_p}(J_c, B, T) \right|$ has three distinctive ranges (which we already mentioned above, but it is important to list these ranges again), each of which can be approximated by a linear curve:

- 1. Low reduced applied magnetic field range, where the approximation is the $|F_p(J_c)|$ line (which corresponds to the schematic diagram shown in Figure 9a);
- 2. High reduced applied magnetic field range, where the approximation is the $|F_p(B)|$ curve;
- 3. Middle reduced applied magnetic field, where the $\left|\vec{F_p}(J_c)\right|$ line and $\left|\vec{F_p}(B)\right|$ curve can be approximated by a median curve or line.

Calculations based on Equations (21), (23) and (33) reveal the following values (for calculations, we used the Ginzburg–Landau $\kappa(T) = 95$ [39,53]):

$$|c_2(T = 75.5 \text{ K})| = 0.087 \pm 0.009 \text{ T}$$
 (34)

$$B_{c1}(T = 75.5 \text{ K}) = 8.8 \times 10^{-3} \text{ T}$$
 (35)

$$\varepsilon(T = 75.5 \text{ K}) = 10 \pm 1$$
 (36)

$$d_{hexagonal}(T = 77.5 \text{ K}) = 166 \text{ nm}$$
 (37)

Before we present the results of the analysis of the temperature dependence of the $\left|\vec{F_{p}}(J_{c},T)\right|$ datasets for one of a few commercially available HTS 2G-wires, it will be interesting to present the $\left|\vec{F_{p}}(J_{c},T=4.2 \text{ K})\right|$ data analysis for a laboratory-made sample, which can be considered as the upper limiting case for commercial HTS 2G-wires. Xu et al. [54] fabricated and studied a ~0.9 µm thick (Gd,Y)Ba₂Cu₃O₇₋₈ + 15% BaZrO₃ thin film, which was deposited on a standard buffered IBAD Hastelloy substrate by the metal–organic chemical vapor deposition technique. The $J_{c}(B, T = 4.2 \text{ K})$ and $\left|\vec{F_{p}}(B, T = 4.2 \text{ K})\right|$ datasets are shown in Figure 15a,b, respectively (datasets are reported in [54]). It should be mentioned that the $\left|\vec{F_{p}}(B, T = 4.2 \text{ K})\right|$ fit to the Kramer–Dew–Hughes model, despite that it converged at a fixed q = 2.0 value, does not have high quality.



Figure 15. Projections of the $\left|\vec{F_p}(J_c, B, T = 4.2 \text{ K}, \theta = 0^\circ)\right|$ curve for the (Gd,Y)Ba₂Cu₃O_{7- δ} + 15% BaZrO₃ thin film into three orthogonal planes. Raw $J_c(B, T = 4.2 \text{ K}, \theta = 0^\circ)$ data panel (**a**) and data fits to Equation (3) panel (**b**) and Equation (33) panel (**c**) are shown. Raw $J_c(B, T = 4.2 \text{ K})$ data were reported by Xu et al. [54]. Goodness of fit (**b**) R = 0.95 and (**c**) R = 0.9975. Shown by shadow areas are 95% confidence bands.

However, the fit of the $\left|\vec{F_p}(J_c, T = 4.2 \text{ K})\right|$ dataset to Equation (33) has converged (Figure 15c), and the linear dependence of $\left|\vec{F_p}(J_c, T = 4.2 \text{ K})\right|$ at high critical current densities is remarkably clear and accurate. It should be stressed that there are no visual designations in either Figure 15a or Figure 15b that there is a very sharp transition between two linear dependences in $\left|\vec{F_p}\right|$ vs. J_c , which can be observed clearly in Figure 15c at $J_c(T = 4.2 \text{ K}) = 23 \text{ MA/cm}^2$.

Calculations based on Equations (21) and (23) reveal the following values (for calculations, we used the Ginzburg–Landau $\kappa(T) = 95$ [53]):

$$c_2(T = 4.2 \text{ K})| = 5.4 \pm 0.1 \text{ T}$$
 (38)

$$B_{c1}(T = 4.2 \text{ K}) = 0.072 \text{ T}$$
(39)

$$\varepsilon(T = 4.2 \text{ K}) = 75 \pm 1$$
 (40)

$$d_{hexagonal}(T = 4.2 \text{ K}) = 21 \text{ nm}$$

$$\tag{41}$$

There are two good matches between deduced values (Equations (38)–(41)) and reported values. The first one is deduced $B_{c1}(T = 4.2 \text{ K}) = 0.072 T$, which is in good agreement with reported values for YBa₂Cu₃O_{7- δ} single crystals [55,56].

The second agreement with that reported by Xu et al. [54] is the average distance between BaZrO₃ nanorods in the REBCO matrix, which was extracted from the analysis of transmission electron microscopy (TEM) images, $d_{average,TEM} \sim 17 - 25$ nm [54]. We deduced the equivalent hexagonal vortex lattice parameter $d_{hexagonal}(T = 4.2 \text{ K}) = 21$ nm (Figure 15 and Equations (23) and (33)). These two characteristic lengths can be considered equal, because the natural variation of the BaZrO₃ nanorod density in the REBCO matrix has reasonable variation, even within the viewing area of the same TEM image (see, for instance, Figure 10 in [15]).

Thus, there is the first direct experimental evidence that the $|c_2(T)|$ field can be interpreted as the matching field related to the density of structural defects in superconductors.

We should stress that the $|c_2(T)|$ field is not a field at which the $\left|\vec{F_p}(J_c, B, T)\right|$ or $J_c(B, T)$ curves have any sort of inflection or other unique features, because the $|c_2(T)|$ field is the linear coefficient between $\left|\vec{F_p}(J_c, B, T)\right|$ and J_c at a low reduced applied magnetic field, $\frac{B}{B_{irr}}$. Perhaps this is the primary point, which designates our approach and all previous attempts to define the matching field. This means that $|c_2(T)|$ is the characteristic field that quantified the pinning strength of the superconductor within a wide range of the applied magnetic field, *B*. This is not a threshold field at which some or any designated features in the $\left|\vec{F_p}(J_c, B, T)\right|$ and $J_c(B, T)$ curves can be observed. The analogy here can be similar to the behavior of $J_c(B)$ at $B = B_{\text{Fp,max}}$ (where $B_{\text{Fp,max}}$ is the applied field at which the pinning force density reaches its maximum) because $J_c(B)$ represents a smooth function at $B = B_{\text{Fp,max}}$ and there is no feature that can manifest that the applied field equals the $B_{\text{Fp,max}}$, until some mathematical operations will be applied to $J_c(B)$.

In this regard, $|c_2(T)|$ represents an integrated linear response of the pinning landscape of the superconductor on the applied magnetic field, from which the characteristic hexagonal lattice parameter, $d_{hexagonal}(T)$, at which Abrikosov's vortices are separated, can be calculated.

This is obvious, but an important issue, that $|c_2(T)|$ is not a field at which the inflection in the $\left|\overrightarrow{F_p}(J_c, T)\right|$ curve (i.e., $\left|F_{p,switch}(J_c, T)\right|$) is observed. On the other hand, it might be useful to perform detailed experimental studies of $\left| \overrightarrow{F_p}(J_c, B \cong |c_2(T)|, T) \right|$ and $|J_c(B \cong |c_2(T)|, T)|$ in a variety of superconductors.

It is interesting to note that deduced $d_{hexagonal}(T = 4.2 \text{ K}) = 21 \text{ nm}$ (Equation (41)) for the (Gd,Y)Ba₂Cu₃O_{7- δ}+15% BaZrO₃ film is in the same ballpark with $d_{hexagonal}(T = 4.2 \text{ K}) = 24 \text{ nm}$ for the NdFeAs(O,F) film, which we deduced above (Figure 12).

To demonstrate the applicability of our approach to analyze commercial HTS 2Gwires, in Figures 16 and 17, we show that the analysis for SuperPower Inc. wire (raw experimental $J_c(B, T, \theta)$ data is available online at an RRI high-temperature superconducting (HTS) wire critical current database [57]). To perform the analysis, we assumed that the REBCO film has a thickness of 1.7 µm, and all $\left|\vec{F_p}(J_c, T, \theta = 0^\circ)\right|$ datasets were fitted to Equation (28).



Figure 16. $\left| \overrightarrow{F_p}(J_c, T, \theta = 0^\circ) \right|$ curves and data fits to Equation (28) for SuperPower HTS 2G-wire measured in the temperature range of 85–65 K (**a**–**f**). Raw transport $J_c(B, T, \theta = 0^\circ)$ data are freely available online [57]. The goodness of fit for all panels is better than R = 0.998. Shown by shadow areas are 95% confidence bands.



Figure 17. $\left|\vec{F_p}(J_c, T, \theta = 0^\circ)\right|$ curves and data fits to Equation (28) for SuperPower HTS 2G-wire measured in the temperature range of 60–40 K (**a**–**e**). Raw transport $J_c(B, T, \theta = 0^\circ)$ data are freely available online [57]. The goodness of fit for all panels is better than R = 0.998. Shown by shadow areas are 95% confidence bands.

Deduced parameters are shown in Figure 18. Overall, the deduced pinning field enhancement factor, $\varepsilon(T)$ (Figures 13–17), in REBCO superconductors is varying within the range:

$$10 \le \varepsilon(T)_{REBCO} \le 80 \tag{42}$$

These values of $\varepsilon(T)_{REBCO}$ are in times lower than $\varepsilon(T)_{NdFeAs(O,F)}$ in the NdFeAs(O,F) thin film (Figure 12).

The collective pinning peak is observable in all $|\vec{F_p}(J_c, T)|$ curves shown in Figures 14, 16 and 17. We should also note that there is a general similarity in the shape of $|\vec{F_p}(J_c, T = 4.2 \text{ K})|$ measured in the NdFeAs(O,F) film (Figure 10a) and (Gd,Y)Ba₂Cu₃O_{7- δ} + 15% BaZrO₃ film (Figure 15c), because both curves have a steep linear raise of $|\vec{F_p}(J_c, T = 4.2 \text{ K})|$ at low applied magnetic fields.



Figure 18. Deduced parameters from the fit of $|\vec{F_p}(J_c, T, \theta = 0^\circ)|$ data to Equation (28) for Super-Power HTS 2G-wire. (a) l(T) and (b) m(T) free-fitting parameters of Equation (28); (c) deduced free-fitting parameter $|c_2(T)|$ (Equation (13)) and $B_{c1}(T)$ calculated by Equation (21) for SuperPower wire for which raw transport $J_c(B, T, \theta = 0^\circ)$ data are freely available online [57]. (d) Pinning field enhancement factor $\varepsilon(T)$ (Equation (18) for the same film. (e) Equivalent hexagonal lattice parameter $d_{hexagonal}(T)$ (Equation (23) for the same film.

3.4. Near-Room-Temperature Superconductors (La,Y)H₁₀ and YH₆

An astonishing experimental discovery of near-room-temperature superconductivity (NRTS) in highly compressed H₃S by Drozdov et al. [58] sparked a worldwide research initiative in the hydrogen-rich superconductivity [59]. Recently, Semenok et al. [60] predicted NRTS in ternary hydride (La,Y)H₁₀ by first-principle calculations and consequently synthesized this ternary hydride, which exhibited T_c up to 253 K, depending on the applied pressure. Semenok et al. [60] reported an in-field transport critical current, $I_c(B, T)$, dataset for (La,Y)H₁₀, which exhibits zero resistance $T_c = 233$ K at pressure P = 186 GPa.

Here, we analyzed $I_c(B, T = 221 \text{ K})$ and R(T) data for the (La,Y)H₁₀ sample compressed at P = 186 GPa (for which raw data are shown in Figure 4 in [60]). By assuming a sample thickness of 1 µm and a sample width of 20 µm, $J_c(B, T = 221 \text{ K})$, $F_p(B, T = 221 \text{ K})$, and $F_p(J_c, T = 221 \text{ K})$ were calculated, and these datasets are shown in Figure 19. We also added in these datasets an experimental value for $B_{irr}(T = 221 \text{ K}) = 10 \text{ T}$ (which can be extracted from data shown in Figure 4b in [60]).



Figure 19. Projections of the $|\vec{F_p}(J_c, B, T = 221 \text{ K})|$ curve for highly compressed (La,Y)H₁₀ (*P* = 168 GPa) into three orthogonal planes. Raw $J_c(B, T = 221 \text{ K})$ data panel (**a**) and data fits for panel (**b**) and panel (**c**) are shown. (**a**) The projection into the $F_p = 0$ plane; (**b**) the projection into the $J_c = 0$ plane and data fit to the Kramer–Dew–Hughes model (Equation (3)), $B_{irr}(T = 221 \text{ K}) = 10 \text{ T}$ (fixed value to the experimentally observed value by Semenok et al. [59]); and (**c**) the projection into the B = 0 plane and data fit to the linear piecewise model (Equation (13)). Raw $I_c(B, T = 221 \text{ K})$ data were reported by Semenok et al. [60]. Assuming that the Ginzburg–Landau parameter is $\kappa(T) = 90$. Shown by shadow areas are 95% confidence bands.

The most impressive deduced value for the (La,Y)H₁₀ sample is the pinning field enhancement factor, $\varepsilon(T = 221 \text{ K})$, which exceeds its counterpart in the IBS NdFeAs(O,F) film (for calculations, we utilized the Ginzburg–Landau parameter $\kappa(T) = 90$, deduced for highly compressed H₃S [61]):

$$|c_2(T = 221 \text{ K})| = 0.89 \pm 0.08 \text{ T}$$
(43)

$$B_{c1}(T = 221 \text{ K}) = (0.9 \pm 0.1) \times 10^{-3} \text{ T}$$
 (44)

$$\varepsilon(T = 221 \text{ K}) = 1000 \pm 100$$
 (45)

$$d_{hexagonal}(T = 221 \text{ K}) = 52 \text{ nm}$$

$$\tag{46}$$

In attempts to confirm this result, we analyzed an in-field transport critical current, $I_c(B, T)$, dataset for another NRTS superconductor, YH₆, which was simultaneously discovered by Troyan et al. [62] and Kong et al. [63]. This superconductor exhibits zero resistance up to $T_c = 243$ K, depending on the applied pressure.

Here, we analyzed the $I_c(B, T = 189 \text{ K})$ dataset for the YH₆ sample compressed at P = 196 GPa (for which raw data are shown in Figure 4a in [62]). By assuming a sample thickness of 1 µm and a sample width of 20 µm, $J_c(B, T = 189 \text{ K})$, $F_p(B, T = 189 \text{ K})$, and $F_p(J_c, T = 189 \text{ K})$ were calculated, and these datasets are shown in Figure 20. For calculations, we utilized the Ginzburg–Landau parameter $\kappa(T) = 90$, deduced for highly compressed H₃S [61].



Figure 20. Projections of the $|\vec{F_p}(J_c, B, T = 189 \text{ K})|$ curve for highly compressed YH₆(P = 196 GPa) into three orthogonal planes. Raw $J_c(B, T = 189 \text{ K})$ data panel (**a**) and data fits for panel (**b**) and panel (**c**) are shown. (**a**) The projection into the $F_p = 0$ plane; (**b**) the projection into the $J_c = 0$ plane and data fit to the Kramer–Dew–Hughes model (Equation (3)), goodness of fit R = 0.9635; and (**c**) the projection into the B = 0 plane and data fit to the linear piecewise model (Equation (13)), goodness of fit R = 0.9090. Raw $I_c(B, T = 189 \text{ K})$ data were reported by Troyan et al. [62]. Assuming that the Ginzburg–Landau parameter is $\kappa(T) = 90$. Shown by shadow areas are 95% confidence bands.

The deduced parameters for YH_6 (P = 196 GPa) at T = 189 K are:

$$|c_2(T = 189 \text{ K})| = 1.02 \pm 0.16 \text{ T}$$
 (47)

$$B_{c1}(T = 189 \text{ K}) = (1.1 \pm 0.2) \times 10^{-3} \text{ T}$$
 (48)

$$\varepsilon(T = 189 \text{ K}) = 950 \pm 200$$
 (49)

$$d_{hexagonal}(T = 189 \text{ K}) = 48 \text{ nm}$$
(50)

Considering that in all studied materials, $\varepsilon(T)$ remains to be the same order of magnitude within a wide temperature range, we can conclude that perhaps all NRTS have high values for the pinning field enhancement factor, $\varepsilon(T)$, and for the matching field (which we proposed should be attributed to the $|c_2(T)|$ field).

4. Discussion

We can note that our analysis on the equivalent hexagonal lattice parameter (presented in Figures 4c, 12c and 18e) showed that there is a clear trend on the reduction of $d_{hexagonal}$ while the sample is cooling down. This trend has a simple explanation, the pinning center array, which is an ensemble of defects in the superconductor (i.e., precipitates, dislocations, point defects, 2D defects), where each defect type has its own size and size statistical distribution, as well as a variation in spatial chemical composition. For instance, the chemical composition of impurity atoms in a cloud around a dislocation can be varied along the dislocation length. For these reasons, different types of defects start to be active pinning centers below some threshold temperature, which is a unique temperature for a given type of defects.

Another complication originates from the fact that it is not impossible that the potential well amplitude of the pinning center is also a function of the applied magnetic field; that is, the pinning strength of the particular center is not necessarily the same at $B_{appl} \sim B_{c1}$ and at $B_{appl} \sim B_{c2}$.

Considering that the effect of thermal depinning of vortices is suppressed while the sample is cooling down, there is a natural expectation that the density of pinning centers increases if sample temperature is decreased. In the result, $d_{hexagonal}$ should reduce while the sample temperature is decreasing. This is exactly what our analyses showed for MgB₂ (Figure 4c), NdFeAs(O,F) (Figure 12c), and REBCO 2G-wire (Figure 18e).

This consideration is valid for defects that are naturally created in the material during gas–solid or solid–solid reactions while the superconducting materials is growing.

However, it is interesting to note that a hexagonal lattice of defects (for instance, holes that penetrate through the full thickness of the film) can be created by microlithography, laser burning, or intensive accelerated ion irradiation [64–67]. Therefore, there are superconducting films where a hexagonal 2D array of pinholes is artificially created [64–67]. These arrays are characterized by the hexagonal lattice parameter, $d_{hexagonal}$, calculated by the same approach we utilized in this report. There is a respectful matching field, $|c_2|$, for this $d_{hexagonal}$ array parameter. It is obvious that these very strong pinning sites (for instance, holes) exhibit temperature independent $d_{hexagonal}$ and $|c_2|$.

In-field transport current experiments performed for these thin films with an artificial hexagonal 2D array of pinholes showed the presence of very sharp peaks at the applied field $B = N \times |c_2|$, where N is an integer number. However, a detailed analysis of the pinning force density in this type of superconductors is beyond the topic of this paper.

Another potentially interesting class of superconductors in which the proposed approach can be applied is (Li,Fe)OHFeSe [68], in which Li et al. [69] discovered several vortex lattice phases, which potentially can be distinguished from each other by our approach.

5. Conclusions

The pinning force density, $F_p(J_c,B)$, is a primary quantity that determines the in-field performance of any superconductor. This fundamental feature of the pinning force density

was first pointed out by P. W. Anderson 60 years ago [1]. Since then, several scaling laws have been proposed for $F_p(J_c, B)$ vs. a reduced applied magnetic field B/B_{appl} [2–16].

In this work, we proposed to scale $F_p(J_c,B)$ vs. a reduced critical current density, $J_c/J_c(sf)$. We applied the proposed approach for experimental data reported for weak-link-free [70] superconducting samples:

- 1. MgB_2 thin films;
- 2. NdFeAs(O,F) thin film;
- 3. REBCO 2G-wire;
- 4. Near-room-temperature superconductors (La,Y)H₁₀ and YH₆ thick films.

Our analysis showed that several important parameters of superconductors (for instance, the equivalent hexagonal lattice parameter and the matching field) can be deduced from experimental $F_p(J_c, B)$ datasets.

It should be noted that the proposed scaling laws describe the in-field performance of superconductors at low and moderate applied magnetic fields. Based on this, a primary niche for the model is to describe wires and tapes for a wide range of practical superconducting devices, which operate at low and moderate magnetic fields. These practical applications are: superconducting cables [71–73], superconducting fault current limiters [74,75], and superconducting transformers [76–79]. The scaling laws proposed in this work extend the established family of scaling laws [4,5,80–84] in superconductivity.

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